

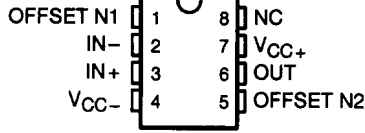
TL081, TL081A, TL081B, TL082, TL082A, TL082B TL082Y, TL084, TL084A, TL084B, TL084Y JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS081B – FEBRUARY 1977 – REVISED AUGUST 1994

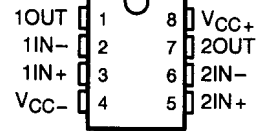
24 DEVICES COVER COMMERCIAL, INDUSTRIAL, AND MILITARY TEMPERATURE RANGES

- Low Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- Output Short-Circuit Protection
- Low Total Harmonic Distortion . . . 0.003% Typ
- High Input Impedance . . . JFET-Input Stage
- Latch-Up-Free Operation
- High Slew Rate . . . 13 V/ μ s Typ
- Common-Mode Input Voltage Range Includes V_{CC+}

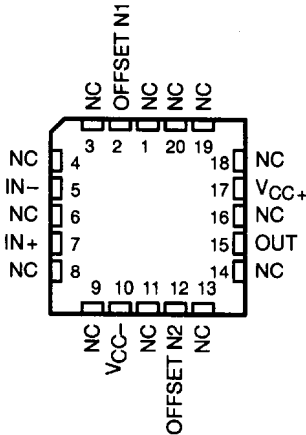
TL081, TL081A, TL081B
D, JG, P, PW, OR U PACKAGE
(TOP VIEW)



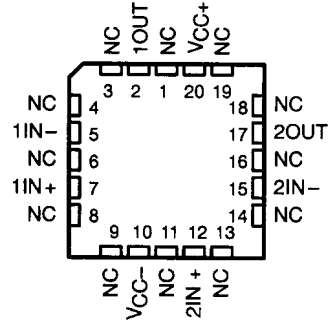
TL082, TL082A, TL082B
D, JG, P, PW, OR U PACKAGE
(TOP VIEW)



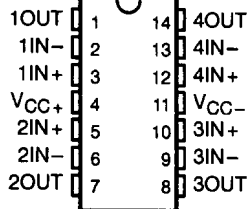
TL081M . . . FK PACKAGE
(TOP VIEW)



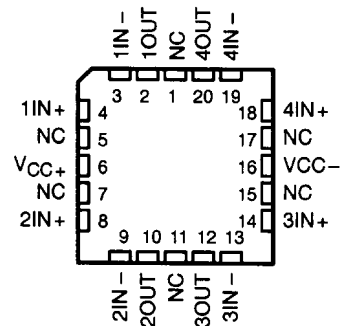
TL082M . . . FK PACKAGE
(TOP VIEW)



TL084, TL084A, TL084B
D, J, N, PW, OR U PACKAGE
(TOP VIEW)



TL084M . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS
INSTRUMENTS**

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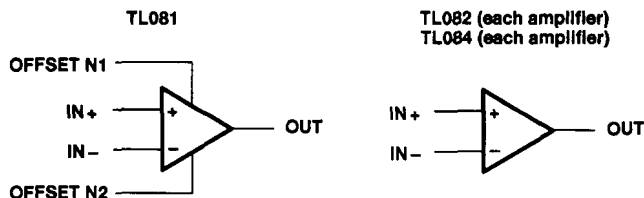
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On products compliant to MIL-STD-883, Class B, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

**TL081, TL081A, TL081B, TL082, TL082A, TL082B
TL082Y, TL084, TL084A, TL084B, TL084Y
JFET-INPUT OPERATIONAL AMPLIFIERS**

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symbols



description

The TL08_ JFET-input operational amplifier family is designed to offer a wider selection than any previously developed operational amplifier family. Each of these JFET-input operational amplifiers incorporates well-matched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit. The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient. Offset adjustment and external compensation options are available within the TL08_ family.

The C-suffix devices are characterized for operation from 0°C to 70°C. The I-suffix devices are characterized for operation from -40°C to 85°C. The M-suffix devices are characterized for operation over the full military temperature range of -55°C to 125°C.



TL081, TL081A, TL081B, TL082, TL082A, TL082B
 TL082Y, TL084, TL084A, TL084B, TL084Y
 JFET-INPUT OPERATIONAL AMPLIFIERS

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AVAILABLE OPTIONS

T _A	V _{IOmax} AT 25°C	PACKAGED DEVICES										CHIP FORM FORM (Y)				
		SMALL OUTLINE (D008)	SMALL OUTLINE (D014)	CHIP CARRIER (FK)	CERAMIC DIP (J)	CERAMIC DIP (JG)	PLASTIC DIP (N)	PLASTIC DIP (P)	TSSOP (PW)	FLAT PACK (U)	FLAT PACK (W)					
0°C to 70°C	15 mV	TL081CD	—	—	—	—	—	—	—	—	—	—	—	—	—	—
	6 mV	TL081ACD	—	—	—	—	—	—	—	—	—	—	—	—	—	—
	3 mV	TL081BCD	—	—	—	—	—	—	—	—	—	—	—	—	—	—
15 mV	6 mV	TL082CD	—	—	—	—	—	—	—	—	—	—	—	—	—	—
	6 mV	TL082ACD	—	—	—	—	—	—	—	—	—	—	—	—	—	—
	3 mV	TL082BCD	—	—	—	—	—	—	—	—	—	—	—	—	—	—
-40°C to 85°C	15 mV	—	TL084CD	—	—	—	—	—	—	—	—	—	—	—	—	—
	6 mV	—	TL084ACD	—	—	—	—	—	—	—	—	—	—	—	—	—
	3 mV	—	TL084BCD	—	—	—	—	—	—	—	—	—	—	—	—	—
-55°C to 125°C	6 mV	TL081ID	TL084ID	—	—	—	—	—	—	—	—	—	—	—	—	—
	6 mV	TL082ID	—	—	—	—	—	—	—	—	—	—	—	—	—	—
	6 mV	TL084ID	—	—	—	—	—	—	—	—	—	—	—	—	—	—
-55°C to 125°C	6 mV	—	—	TL081MFK	—	—	—	—	—	—	—	—	—	—	—	—
	6 mV	—	—	TL082MFK	—	—	—	—	—	—	—	—	—	—	—	—
	9 mV	—	—	TL084MFK	TL084MJ	TL081MJG	TL082MJG	—	—	—	—	—	—	—	—	—
																TL084MW

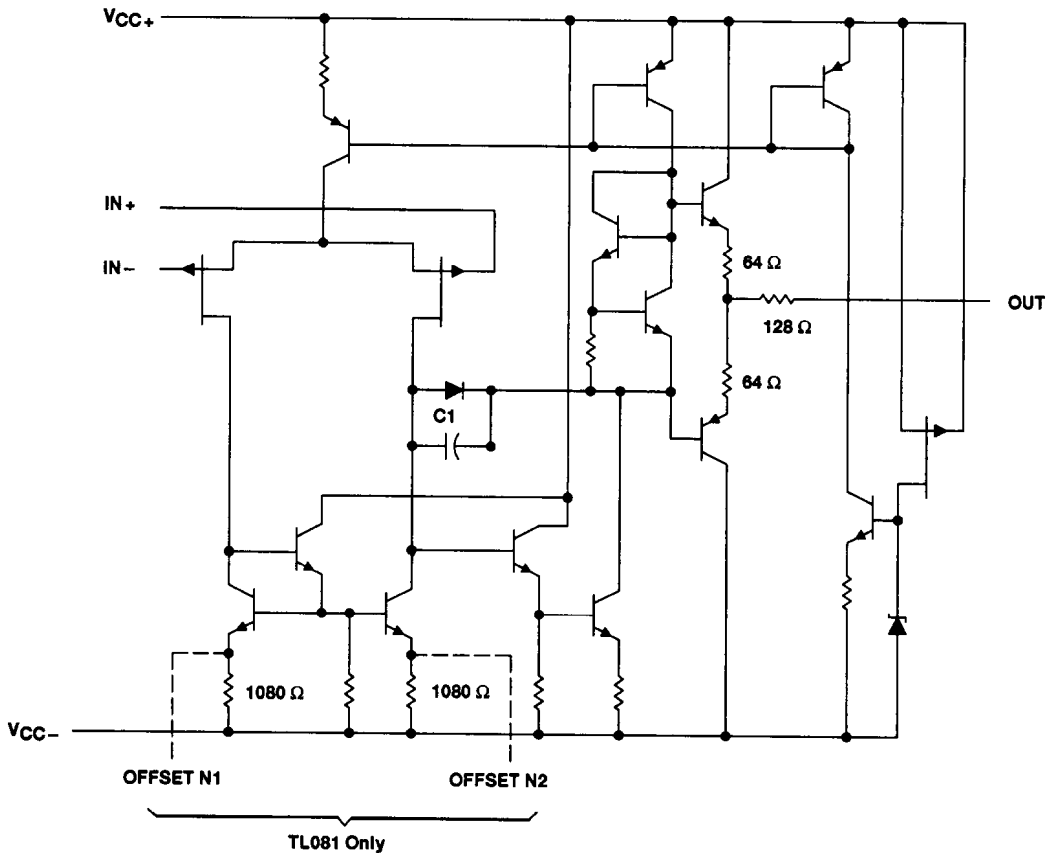
The D package is available taped and reeled. Add R suffix to device type (e.g., TL081CDR).



**TL081, TL081A, TL081B, TL082, TL082A, TL082B
 TL082Y, TL084, TL084A, TL084B, TL084Y
 JFET-INPUT OPERATIONAL AMPLIFIERS**

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schematic (each amplifier)



Component values shown are nominal.



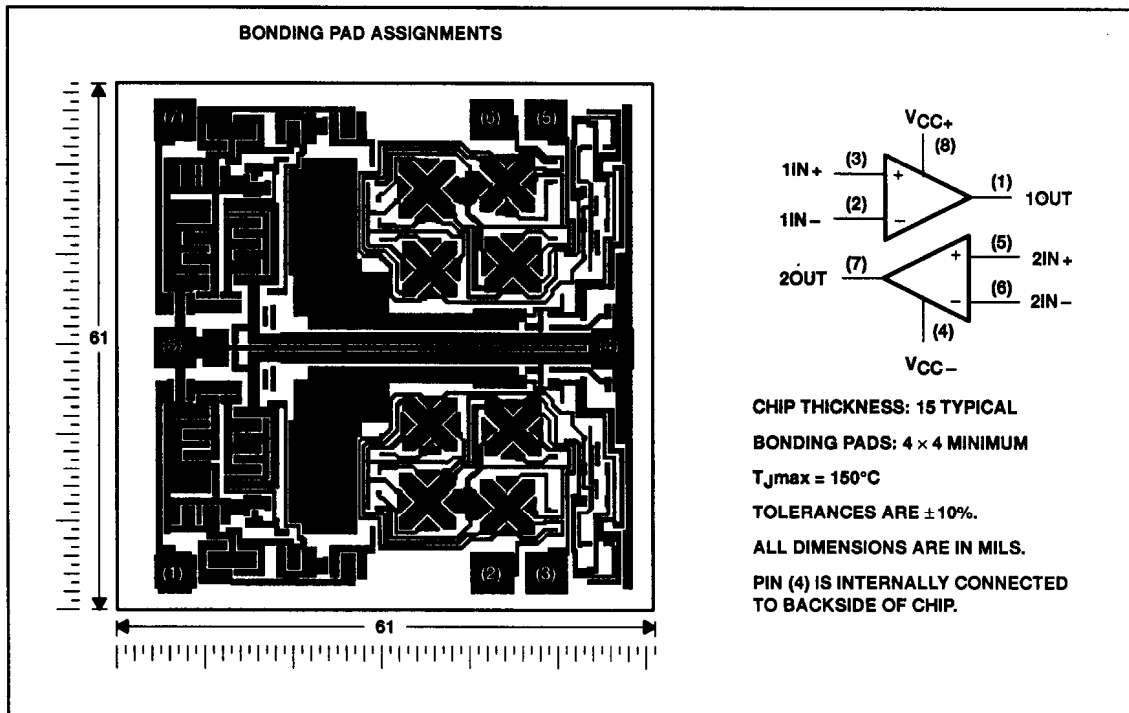
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TL081, TL081A, TL081B, TL082, TL082A, TL082B
 TL082Y, TL084, TL084A, TL084B, TL084Y
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TL082Y chip information

These chips, when properly assembled, display characteristics similar to the TL082. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



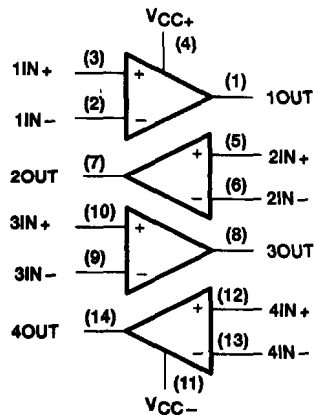
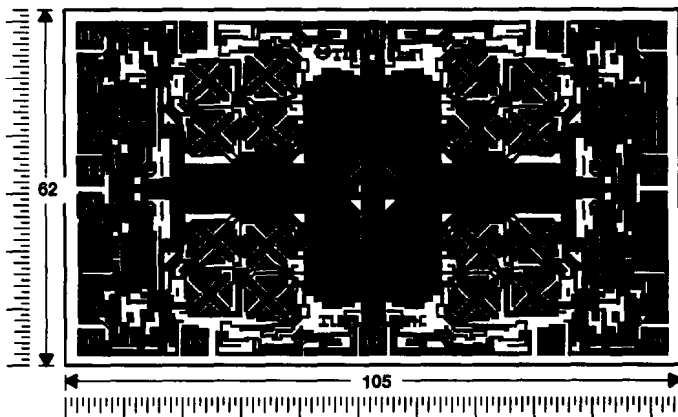
**TL081, TL081A, TL081B, TL082, TL082A, TL082B
 TL082Y, TL084, TL084A, TL084B, TL084Y
 JFET-INPUT OPERATIONAL AMPLIFIERS**

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TL084Y chip information

These chips, when properly assembled, display characteristics similar to the TL084. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.

BONDING PAD ASSIGNMENTS



CHIP THICKNESS: 15 TYPICAL

BONDING PADS: 4 x 4 MINIMUM

T_{Jmax} = 150°C

TOLERANCES ARE ± 10%.

ALL DIMENSIONS ARE IN MILS.

PIN (11) IS INTERNALLY CONNECTED TO BACKSIDE OF CHIP.



**TL081, TL081A, TL081B, TL082, TL082A, TL082B
TL082Y, TL084, TL084A, TL084B, TL084Y
JFET-INPUT OPERATIONAL AMPLIFIERS**

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

	TL08_C TL08_AC TL08_BC	TL08_I	TL08_M	UNIT
Supply voltage, V_{CC+} (see Note 1)	18	18	18	V
Supply voltage V_{CC-} (see Note 1)	-18	-18	-18	V
Differential input voltage, V_{ID} (see Note 2)	± 30	± 30	± 30	V
Input voltage, V_i (see Notes 1 and 3)	± 15	± 15	± 15	V
Duration of output short circuit (see Note 4)	unlimited	unlimited	unlimited	
Continuous total dissipation	See Dissipation Rating Table			
Operating free-air temperature range, T_A	0 to 70	-40 to 85	-55 to 125	°C
Storage temperature range	-65 to 150	-65 to 150	-65 to 150	°C
Case temperature for 60 seconds	FK package		260	°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J or JG package		300	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D, N, P, or PW package	260	260	°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values except differential voltages are with respect to the midpoint between V_{CC+} and V_{CC-} .
 2. Differential voltages are at $IN+$ with respect to $IN-$.
 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T_A	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D (8 pin)	680 mW	5.8 mW/°C	32°C	464 mW	377 mW	N/A
D (14 pin)	680 mW	7.6 mW/°C	60°C	608 mW	494 mW	N/A
FK	680 mW	11.0 mW/°C	88°C	680 mW	680 mW	275 mW
J	680 mW	11.0 mW/°C	88°C	680 mW	680 mW	275 mW
JG	680 mW	8.4 mW/°C	69°C	672 mW	546 mW	210 mW
N	680 mW	9.2 mW/°C	76°C	680 mW	598 mW	N/A
P	680 mW	8.0 mW/°C	65°C	640 mW	520 mW	N/A
PW (8 pin)	525 mW	4.2 mW/°C	25°C	336 mW	N/A	N/A
PW (14 pin)	700 mW	5.6 mW/°C	25°C	448 mW	N/A	N/A
U	675 mW	5.4 mW/°C	25°C	432 mW	351 mW	135 mW
W	680 mW	8.0 mW/°C	65°C	640 mW	520 mW	200 mW

**TL081, TL081A, TL081B, TL082, TL082A, TL082B
TL082Y, TL084, TL084A, TL084B, TL084Y
JFET-INPUT OPERATIONAL AMPLIFIERS**
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electrical characteristics, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TL081C TL082C TL084C			TL081AC TL082AC TL084AC			TL081BC TL082BC TL084BC			TL081 TL082 TL084			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	25°C	3	15	3	6	2	3	3	6	2	3	3	6	mV
		Full range		20		7.5		5						9	
αV_{IO}	Temperature coefficient of input offset voltage	Full range	18		18		18		18		18		18		$\mu V/^\circ C$
I_{IO}	Input offset current ‡	25°C	5	200	5	100	5	100	5	100	5	100	5	100	pA
		Full range		2		2		2		2		2		10	nA
I_{IB}	Input bias current ‡	25°C	30	400	30	200	30	200	30	200	30	200	30	200	pA
		Full range		10		7		7		7		7		20	nA
V_{ICR}	Common-mode input voltage range	25°C	-12 to 15		-12 to 15		-12 to 15		-12 to 15		-12 to 15		-12 to 15		V
		25°C	± 11		± 11		± 11		± 11		± 11		± 11		
		25°C	± 12		± 12		± 12		± 12		± 12		± 12		
		Full range	± 10		± 10		± 10		± 10		± 10		± 10		
V_{OM}	Maximum peak output voltage swing	25°C	± 12	± 13.5	± 12	± 13.5	± 12	± 13.5	± 12	± 13.5	± 12	± 13.5	± 12	± 13.5	V
		Full range	± 12		± 12		± 12		± 12		± 12		± 12		
		25°C	25	200	25	200	25	200	25	200	25	200	25	200	V/mV
		Full range	15		25		25		25		25		25		
B_1	Unity-gain bandwidth	25°C	3		3		3		3		3		3		MHz
f_i	Input resistance	25°C	10 ¹²		10 ¹²		10 ¹²		10 ¹²		10 ¹²		10 ¹²		Ω
CMRR	Common-mode rejection ratio	25°C	70	86	75	86	75	86	75	86	75	86	75	86	dB
KSVR	Supply voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	25°C	70	86	80	86	80	86	80	86	80	86	80	86	dB
I _{CC}	Supply current (per amplifier)	25°C	1.4	2.8	1.4	2.8	1.4	2.8	1.4	2.8	1.4	2.8	1.4	2.8	mA
V_{O1}/V_{O2}	Crosstalk attenuation	25°C	120		120		120		120		120		120		dB

† All characteristics are measured under open-loop conditions with zero common-mode voltage unless otherwise specified. Full range for T_A is 0°C to 70°C for TL08_C, TL08_AC, TL08_BC and -40°C to 85°C for TL08_I.

‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive as shown in Figure 18. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.



**TL081, TL081A, TL081B, TL082, TL082A, TL082B
TL082Y, TL084, TL084A, TL084B, TL084Y
JFET-INPUT OPERATIONAL AMPLIFIERS**

SLOS081B - FEBRUARY 1977 - REVISED AUGUST 1994

electrical characteristics, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	T _A	TL081M, TL082M			TL084M			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
V _{IO} Input offset voltage	V _O = 0, R _S = 50 Ω	25°C	3	6	3	9	mV		
		-55°C to 125°C		9		15	mV		
α _{VIO} Temperature coefficient of input offset voltage	V _O = 0, R _S = 50 Ω	-55°C to 125°C	18			18			μV/°C
I _{IO} Input offset current‡	V _O = 0	25°C	5	100	5	100	pA		
		125°C	20			20			nA
I _{IB} Input bias current‡	V _O = 0	25°C	30	200	30	200	pA		
		125°C	50			50			nA
V _{ICR} Common-mode input voltage range		25°C	±11	-12 to 15	±11	-12 to 15	V		
V _{OM} Maximum peak output voltage swing	R _L = 10 kΩ	25°C	±12	±13.5	±12	±13.5	V		
	R _L ≥ 10 kΩ	-55°C to 125°C	±12			±12			V
	R _L ≥ 2 kΩ		±10	±12	±10	±12	V		
A _{VD} Large-signal differential voltage amplification	V _O = ±10 V, R _L ≥ 2 kΩ	25°C	25	200	25	200	V/mV		
	V _O = ±10 V, R _L ≥ 2 kΩ	-55°C to 125°C	15			15			V/mV
B ₁ Unity-gain bandwidth		25°C	3			3			MHz
r _i Input resistance		25°C	10 ¹²			10 ¹²			Ω
CMRR Common-mode rejection ratio	V _{IC} = V _{ICRmin} , V _O = 0, R _S = 50 Ω	25°C	80	86	80	86	dB		
k _{SVR} Supply voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC} = ±15 V to ±9 V, V _O = 0, R _S = 50 Ω	25°C	80	86	80	86	dB		
I _{CC} Supply current (per amplifier)	V _O = 0, No load	25°C	1.4	2.8	1.4	2.8	mA		
V _{O1} /V _{O2} Crosstalk attenuation	A _{VD} = 100	25°C	120			120			dB

† All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified.

‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive as shown in Figure 18. Pulse techniques must be used that will maintain the junction temperatures as close to the ambient temperature as is possible.

operating characteristics, $V_{CC\pm} = \pm 15$ V, T_A = 25°C (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR Slew rate at unity gain	V _I = 10 V, R _L = 2 kΩ, C _L = 100 pF, See Figure 1	8*	13		V/μs
	V _I = 10 V, R _L = 2 kΩ, C _L = 100 pF, T _A = -55°C to 125°C, See Figure 1	5*			
t _r Rise time	V _I = 20 mV, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		0.05		μs
Overshoot factor			20%		
V _n Equivalent input noise voltage	R _S = 20 Ω	f = 1 kHz	18		nV/√Hz
		f = 10 Hz to 10 kHz	4		μV
I _n Equivalent input noise current	R _S = 20 Ω, f = 1 kHz		0.01		pA/√Hz
THD Total harmonic distortion	V _{O(rms)} = 10 V, R _S ≤ 1 kΩ, R _L ≥ 2 kΩ, f = 1 kHz		0.003%		

*On products compliant to MIL-STD-883, Class B, this parameter is not production tested.



**TL081, TL081A, TL081B, TL082, TL082A, TL082B
TL082Y, TL084, TL084A, TL084B, TL084Y
JFET-INPUT OPERATIONAL AMPLIFIERS**

SLOS081B – FEBRUARY 1977 – REVISED AUGUST 1994

electrical characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	TL082Y, TL084Y			UNIT
			MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_O = 0$, $R_S = 50\ \Omega$		3	15	mV
α_{VIO}	Temperature coefficient of input offset voltage	$V_O = 0$, $R_S = 50\ \Omega$		18		$\mu\text{V}/^\circ\text{C}$
I_{IO}	Input offset current‡	$V_O = 0$		5	200	pA
I_{IB}	Input bias current‡	$V_O = 0$		30	400	pA
V_{ICR}	Common-mode input voltage range		± 11	-12 to 15		V
V_{OM}	Maximum peak output voltage swing	$R_L = 10\ \text{k}\Omega$	± 12	± 13.5		V
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$, $R_L \geq 2\ \text{k}\Omega$	25	200		V/mV
B_1	Unity-gain bandwidth			3		MHz
r_i	Input resistance			10^{12}		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $V_O = 0$, $R_S = 50\ \Omega$	70	86		dB
kSVR	Supply voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC} = \pm 15\ \text{V}$ to $\pm 9\ \text{V}$, $V_O = 0$, $R_S = 50\ \Omega$	70	86		dB
I_{CC}	Supply current (per amplifier)	$V_O = 0$, No load		1.4	2.8	mA
V_{O1}/V_{O2}	Crosstalk attenuation	$A_{VD} = 100$		120		dB

† All characteristics are measured under open-loop conditions with zero common-mode voltage unless otherwise specified.

‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive as shown in Figure 18. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

operating characteristics, $V_{CC\pm} = \pm 15\ \text{V}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
SR	Slew rate at unity gain	$V_i = 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$, $C_L = 100\ \text{pF}$, See Figure 1	8	13		V/ μs
t_r	Rise time	$V_i = 20\ \text{mV}$, $R_L = 2\ \text{k}\Omega$, $C_L = 100\ \text{pF}$, See Figure 1		0.05		μs
	Overshoot factor			20%		
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$	$f = 1\ \text{kHz}$	18		nV/ $\sqrt{\text{Hz}}$
			$f = 10\ \text{Hz}$ to $10\ \text{kHz}$	4		μV
I_n	Equivalent input noise current	$R_S = 20\ \Omega$, $f = 1\ \text{kHz}$		0.01		pA/ $\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$V_{O(rms)} = 10\ \text{V}$, $R_S \leq 1\ \text{k}\Omega$, $R_L \geq 2\ \text{k}\Omega$, $f = 1\ \text{kHz}$		0.003%		



PARAMETER MEASUREMENT INFORMATION

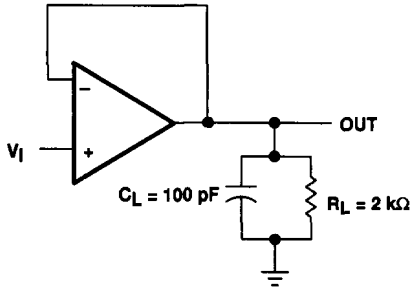


Figure 1. Unity-Gain Amplifier

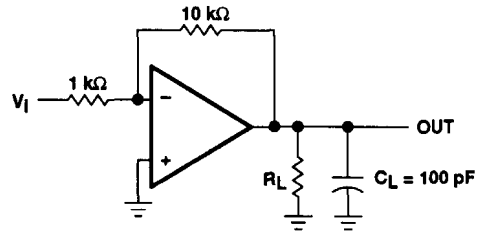


Figure 2. Gain-of-10 Inverting Amplifier

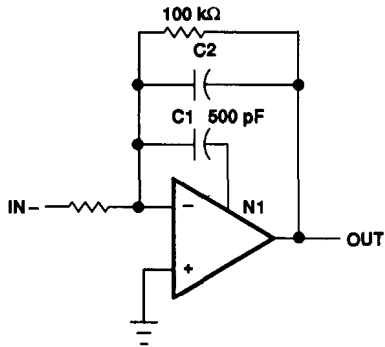


Figure 3. Feed-Forward Compensation

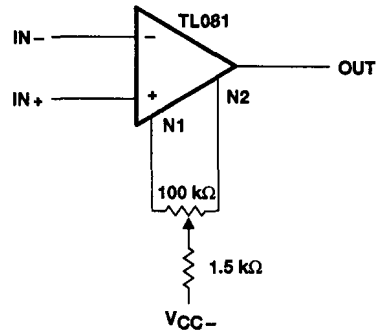


Figure 4. TL081 Input Offset Voltage Null Circuit

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V _{OM}	Maximum peak output voltage	vs Frequency	5, 6, 7
		vs Free-air temperature	8
		vs Load resistance	9
		vs Supply voltage	10
A _{VD}	Large-signal differential voltage amplification	vs Free-air temperature	11
		vs Frequency	12
	Differential voltage amplification	vs Frequency with feed-forward compensation	13
P _D	Total power dissipation	vs Free-air temperature	14
I _{CC}	Supply current	vs Free-air temperature	15
		vs Supply voltage	16
I _{IB}	Input bias current	vs Free-air temperature	17
	Large-signal pulse response	vs Time	18
V _O	Output voltage	vs Elapsed time	19
CMRR	Common-mode rejection ratio	vs Free-air temperature	20
V _n	Equivalent input noise voltage	vs Frequency	21
THD	Total harmonic distortion	vs Frequency	22

**MAXIMUM PEAK OUTPUT VOLTAGE
 vs
 FREQUENCY**

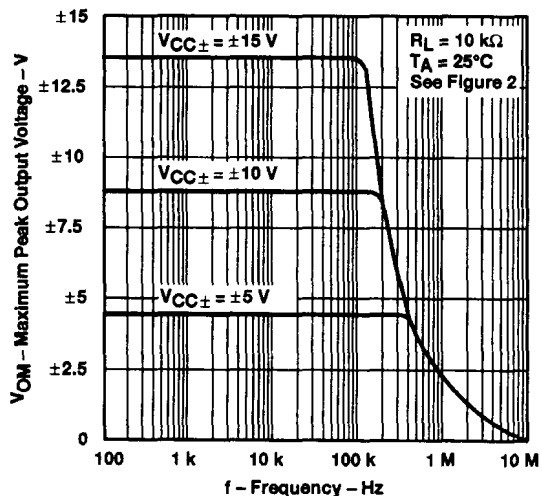


Figure 5

**MAXIMUM PEAK OUTPUT VOLTAGE
 vs
 FREQUENCY**

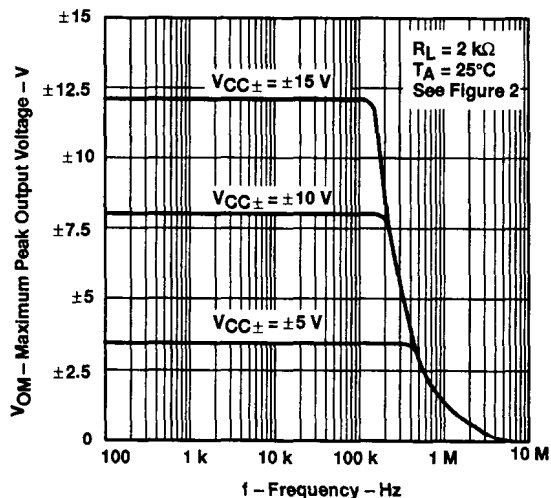


Figure 6

TYPICAL CHARACTERISTICS†

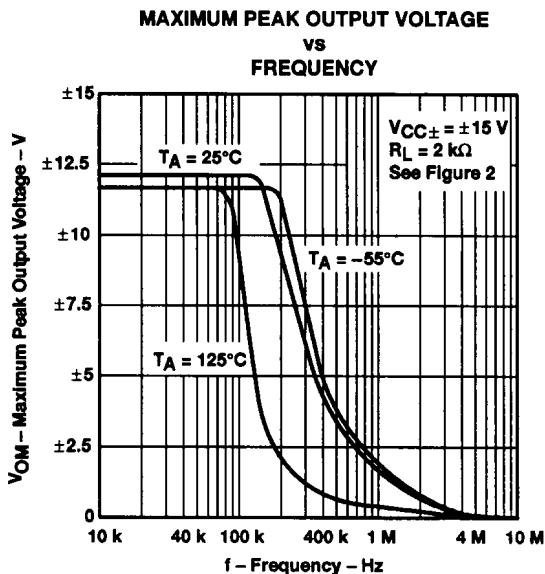


Figure 7

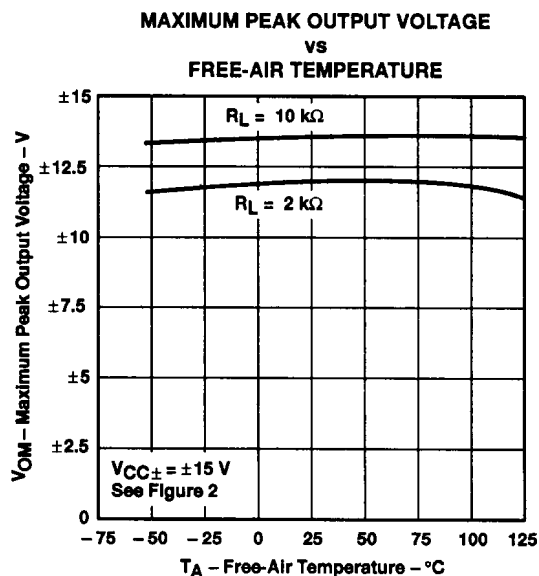


Figure 8

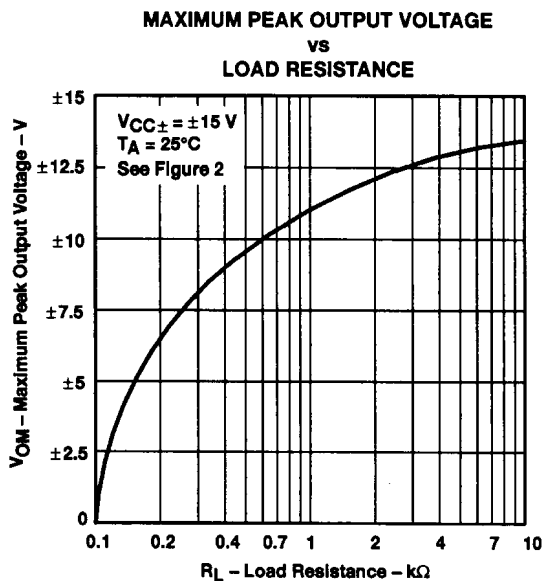


Figure 9

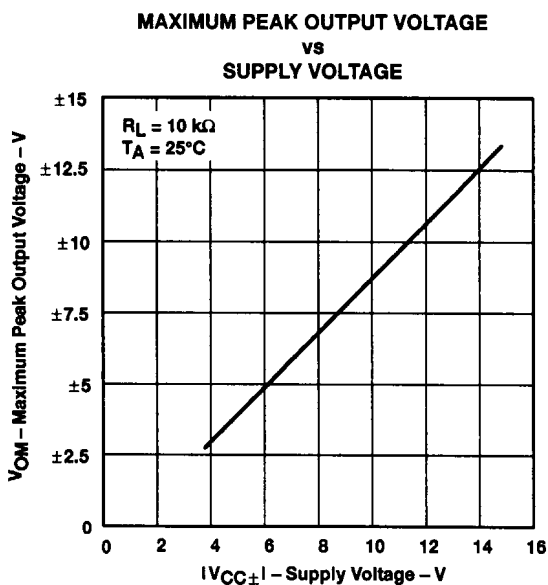


Figure 10

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TL081, TL081A, TL081B, TL082, TL082A, TL082B
 TL082Y, TL084, TL084A, TL084B, TL084Y
JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS081B – FEBRUARY 1977 – REVISED AUGUST 1994

TYPICAL CHARACTERISTICS†

**LARGE-SIGNAL
 DIFFERENTIAL VOLTAGE AMPLIFICATION
 vs
 FREE-AIR TEMPERATURE**

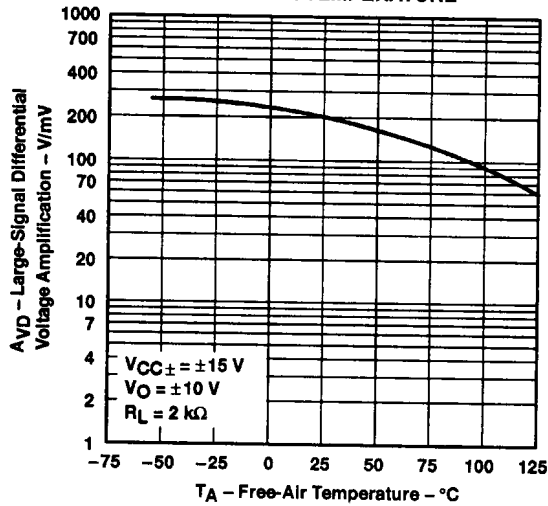


Figure 11

**LARGE-SIGNAL
 DIFFERENTIAL VOLTAGE AMPLIFICATION
 vs
 FREQUENCY**

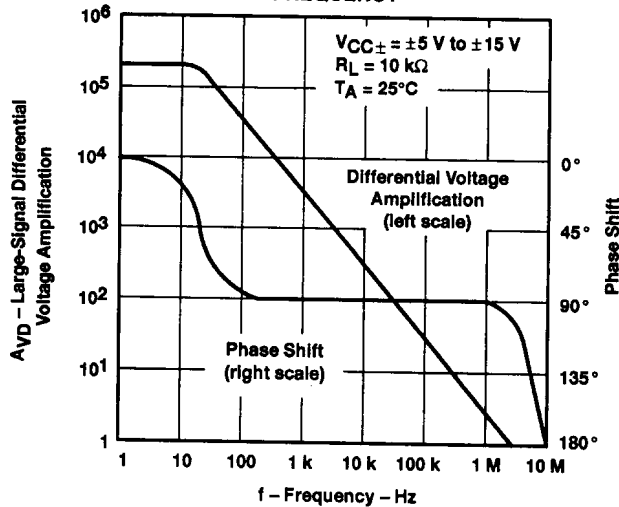


Figure 12

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

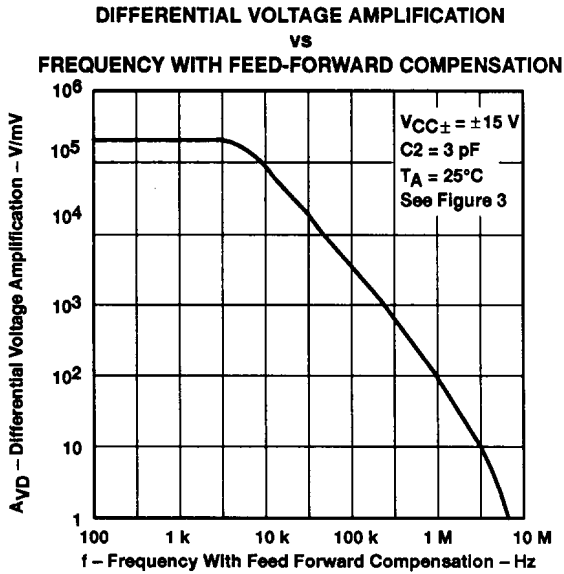


Figure 13

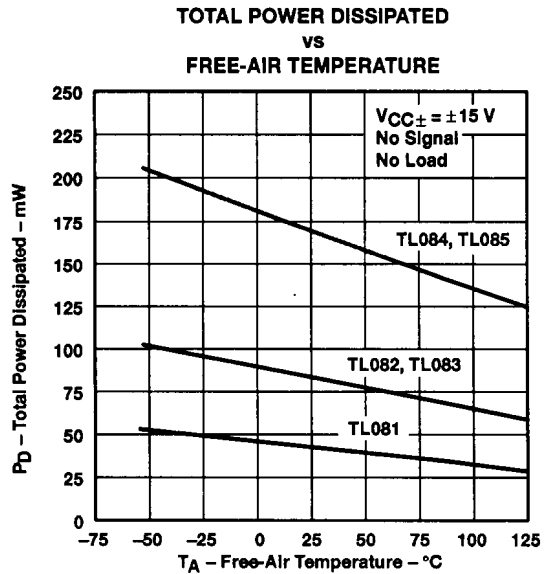


Figure 14

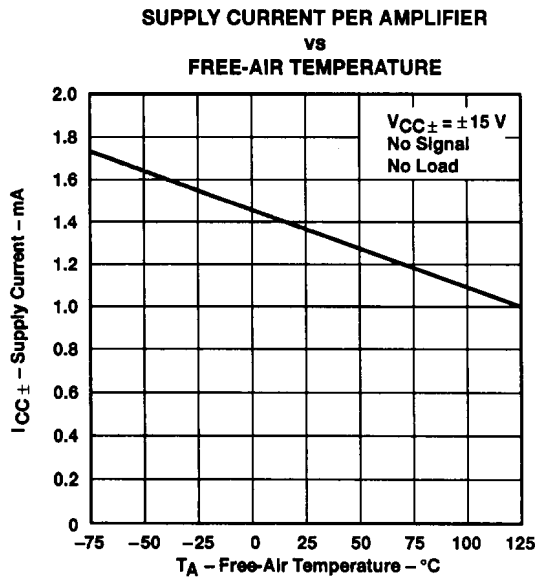


Figure 15

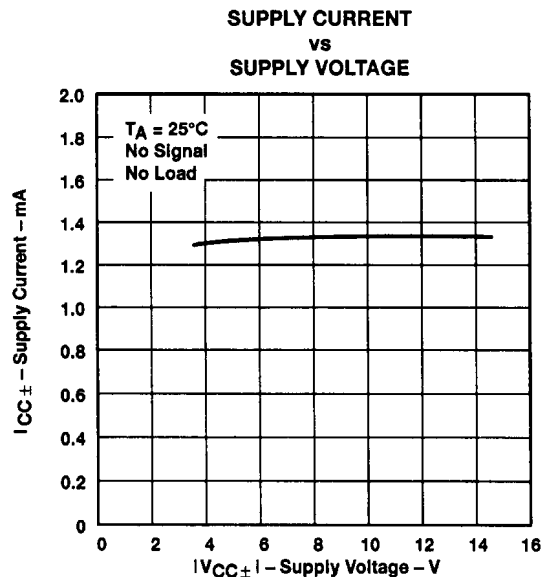


Figure 16

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

**INPUT BIAS CURRENT
 vs
 FREE-AIR TEMPERATURE**

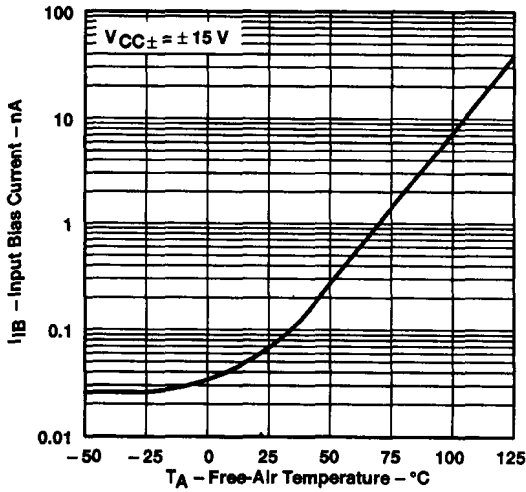


Figure 17

**VOLTAGE-FOLLOWER
 LARGE-SIGNAL PULSE RESPONSE**

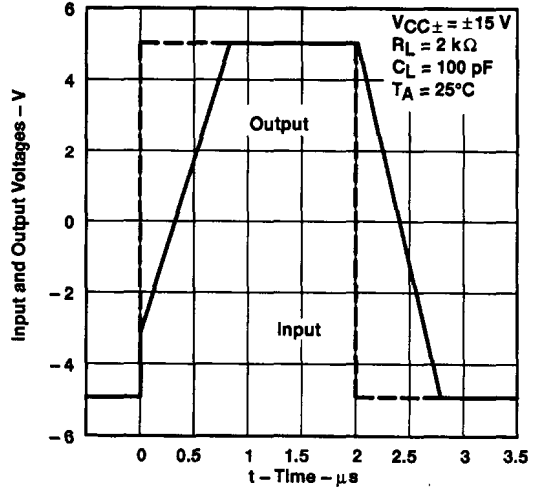


Figure 18

**OUTPUT VOLTAGE
 vs
 ELAPSED TIME**

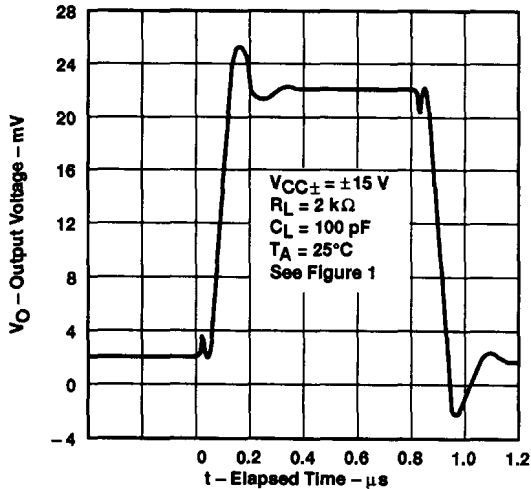


Figure 19

**COMMON-MODE REJECTION RATIO
 vs
 FREE-AIR TEMPERATURE**

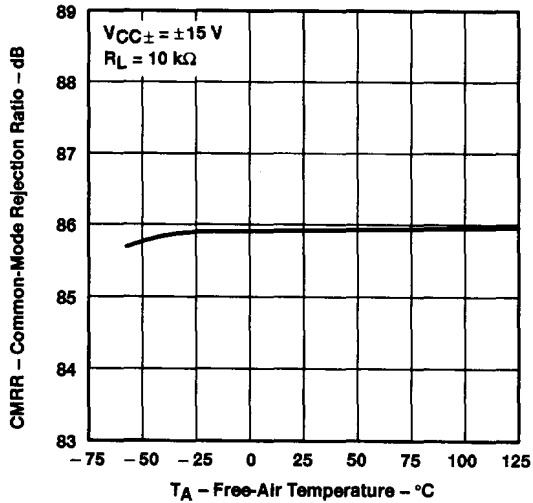


Figure 20

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

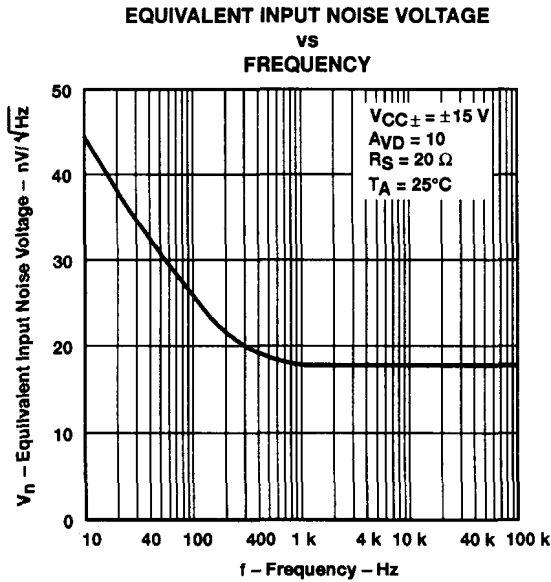


Figure 21

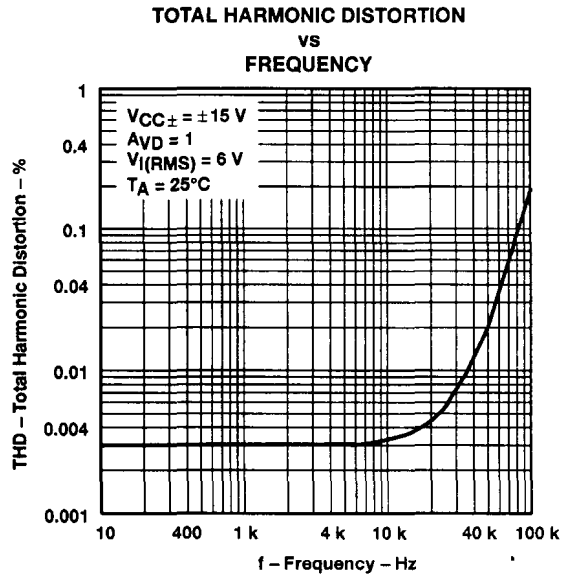


Figure 22

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

APPLICATION INFORMATION

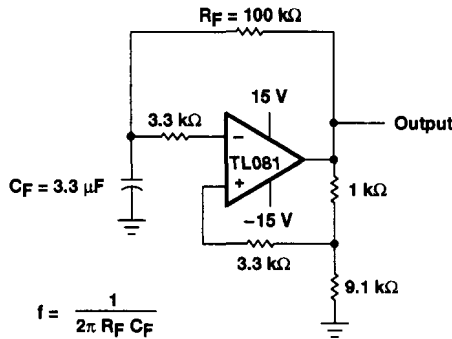


Figure 23. 0.5-Hz Square-Wave Oscillator

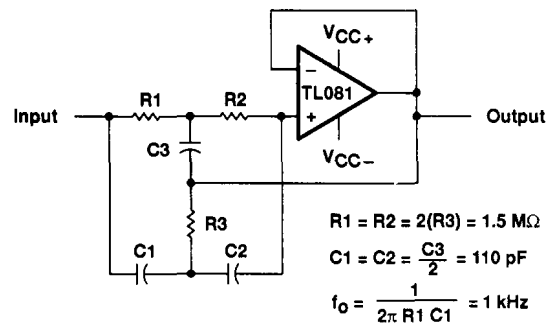


Figure 24. High-Q Notch Filter

APPLICATION INFORMATION

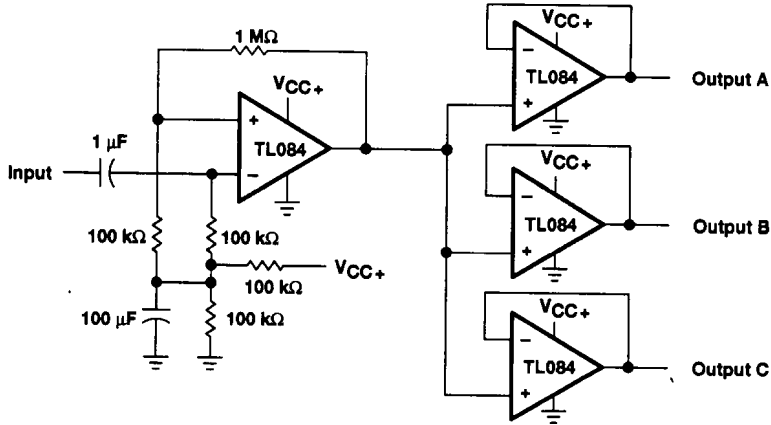
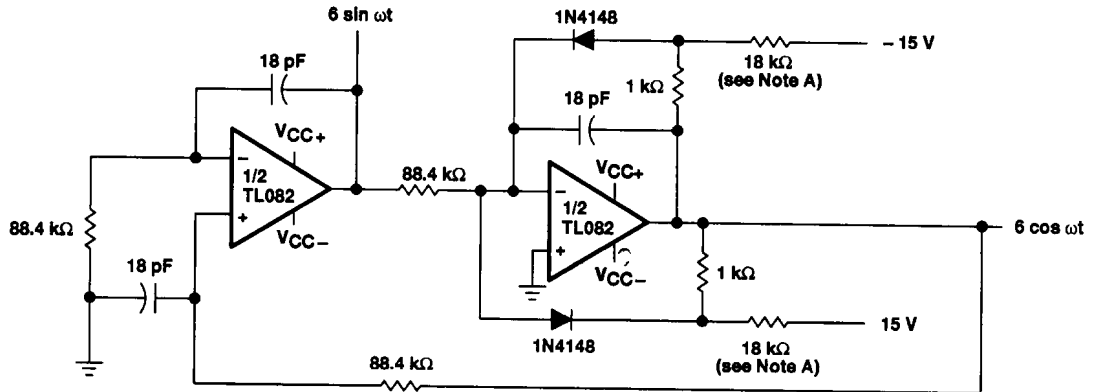


Figure 25. Audio-Distribution Amplifier



NOTE A: These resistor values may be adjusted for a symmetrical output.

Figure 26. 100-KHz Quadrature Oscillator

APPLICATION INFORMATION

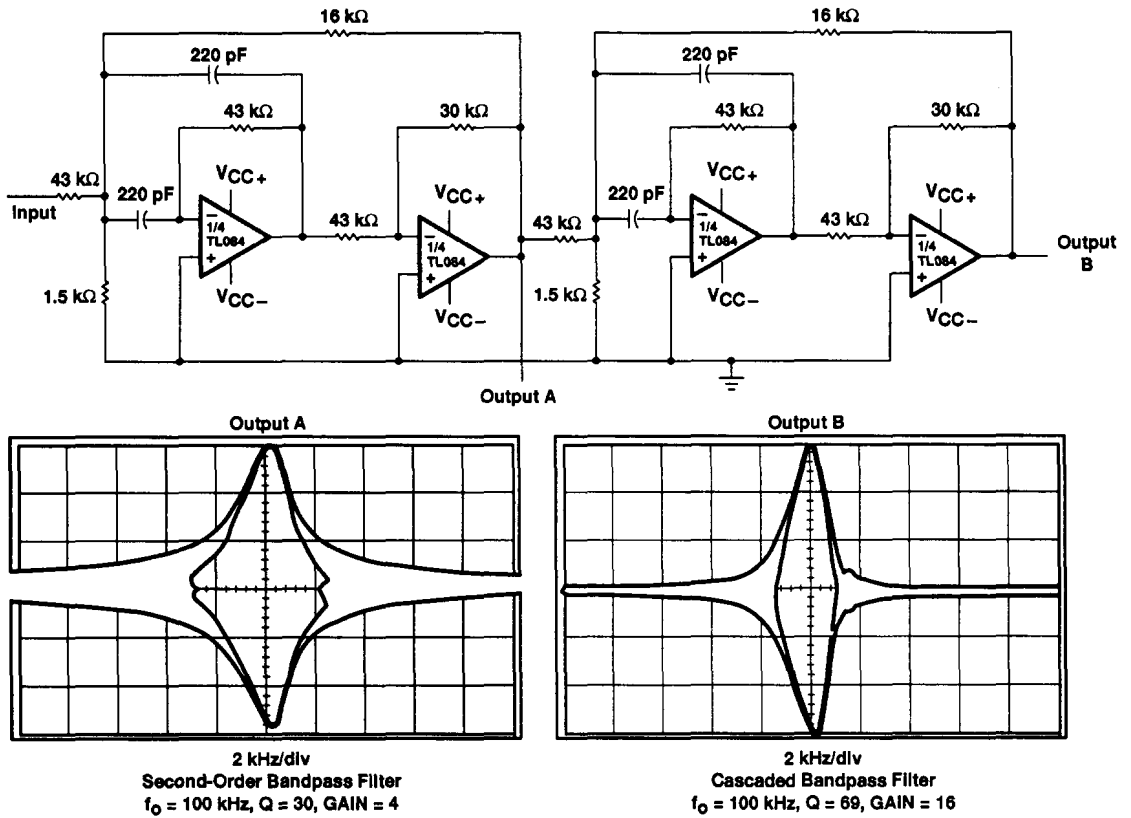


Figure 27. Positive-Feedback Bandpass Filter